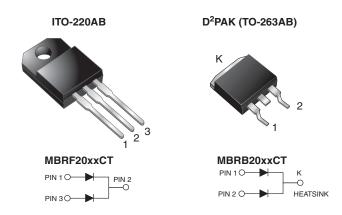
MBRF20xxCT, MBRB20xxCT

Vishay General Semiconductor

Dual Common Cathode Schottky Rectifier



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 10 A				
V_{RRM}	35 V, 45 V, 60 V				
I _{FSM}	150 A				
V_{F}	0.57 V, 0.70 V				
T _J max.	150 °C				
Package	ITO-220AB, D ² PAK (TO-263AB)				
Diode variations	Common cathode				

FEATURES

- Power pack
- · Guardring for overvoltage protection
- · Low power loss, high efficiency
- Low forward voltage drop
- · High forward surge capability
- · High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for D2PAK (TO-263AB) package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for ITO-220AB package)
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, and polarity protection application.

MECHANICAL DATA

Case: ITO-220AB, D2PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified Base P/NHE3_X - RoHS-compliant, AEC-Q101 qualified ("_X" denotes revision code, e.g. A, B, ...)

Terminals: matte tin plated leads, solderable J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MBRB2035CT	MBRB2045CT	MBRB2060CT	UNIT	
Maximum repetitive peak reverse voltage	V_{RRM}	35	45	60		
Working peak reverse voltage	V _{RWM}	35	45	60	V	
Maximum DC blocking voltage	V_{DC}	35	45	60	1	
Maximum average forward rectified current total device		20				
at T _C = 135 °C per diode	I _{F(AV)}	10				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	150			Α	
Peak repetitive reverse surge current per diode at t_p = 2.0 1 kHz	μs, I _{RRM}	1.0 0.5		0.5		
Voltage rate of change (rated V _R)	dV/dt	10 000			V/µs	
Operating junction temperature range	TJ	-65 to +150			°C	
Storage temperature range	T _{STG}	-65 to +175				
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		1500			V	



MBRF20xxCT, MBRB20xxCT

Vishay General Semiconductor

ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS		MBRB2035CT, MBRB2045CT	MBRB2060CT	UNIT
Maximum instantaneous forward voltage per diode		I _F = 10 A	T _C = 25 °C	0.65	0.80	
	V _F ⁽¹⁾	I _F = 10 A	T _C = 125 °C	0.57	0.70	V
		I _F = 20 A	T _C = 25 °C	0.84	0.95	
		I _F = 20 A	T _C = 125 °C	0.72	0.85	
Maximum reverse current at DC blocking voltage per diode	I _R ⁽²⁾	Data d V	T _C = 25 °C	0.1	0.15	mA
	'R '	Rated V _R	T _C = 125 °C	15	150	IIIA

Notes

 $^{(1)}$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBRF	MBRB	UNIT	
Typical resistance from junction to case per diode	$R_{\theta JC}$	5.0	2.0	°C/W	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
ITO-220AB	MBRF2045CT-E3/45	1.99	45	50/tube	Tube	
TO-263AB	MBRB2045CT-E3/45	1.35	45	50/tube	Tube	
TO-263AB	MBRB2045CT-E3/81	1.35	81	800/reel	Tape and reel	
ITO-220AB	MBRF2045CTHE3/45 1)	1.99	45	50/tube	Tube	
TO-263AB	MBRB2045CTHE3_A/P (1)(2)	1.35	Р	50/tube	Tube	
TO-263AB	MBRB2045CTHE3_A/I (1)(2)	1.35	I	800/reel	Tape and reel	

Notes

⁽¹⁾ AEC-Q101 qualified

^{(2) 35} V device available in AEC-Q101 qualified D2PAK (TO-263AB) only



Vishay General Semiconductor

RATINGS AND CHARACTERISTICS CURVES (T_C = 25 °C unless otherwise noted)

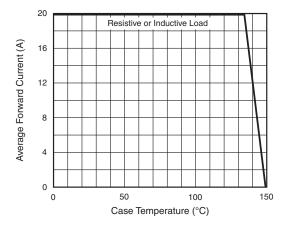
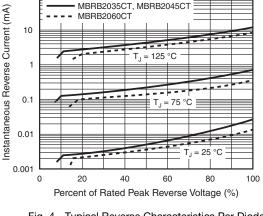


Fig. 1 - Forward Derating Curve (Total)



100

Fig. 4 - Typical Reverse Characteristics Per Diode

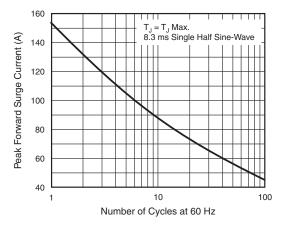


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

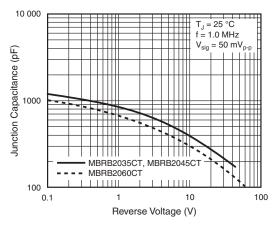


Fig. 5 - Typical Junction Capacitance Per Diode

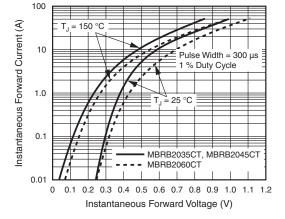


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

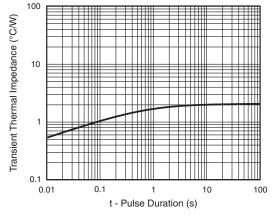
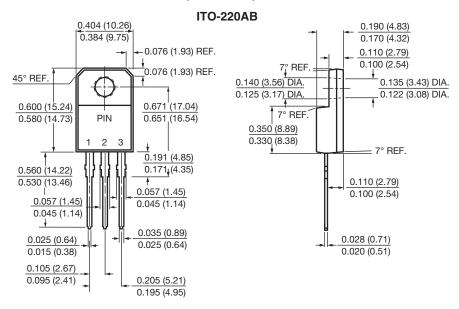


Fig. 6 - Typical Transient Thermal Impedance Per Diode

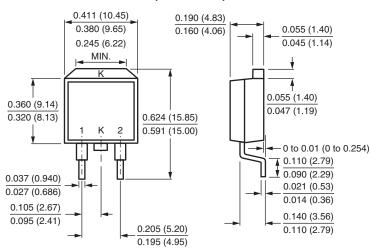


Vishay General Semiconductor

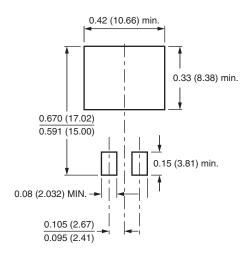
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



D²PAK (TO-263AB)



Mounting Pad Layout





Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.